

## MPS6518/FTSO6518

PNP Small Signal General Purpose Amplifier

T-29.23

• V<sub>CEO</sub> ... 40 V (Min)

• h<sub>FE</sub> ... 150-300 @ 2.0 mA, 90 (Min) @ 100 mA

PACKAGE

MPS6518

TO-92

FTSO6518

TO-236AA/AB

## ABSOLUTE MAXIMUM RATINGS (Note 1)

Temperatures

Storage Temperature -55° C to 150° C Operating Junction Temperature 150° C

Power Dissipation (Notes 2 & 3)

Total Dissipation at MPS FTSO 25° C Ambient Temperature 0.625 W 0.350 W\* 70° C Ambient Temperature 0.400 W 25° C Case Temperature 1.0 W

**Voltages & Currents** 

 
 V<sub>CEO</sub>
 Collector to Emitter Voltage (Note 4)
 -40 V

 V<sub>CBO</sub>
 Collector to Base Voltage
 -40 V

 V<sub>EBO</sub>
 Emitter to Base Voltage
 -4.0 V

 I<sub>C</sub>
 Collector Current
 100 mA

## ELECTRICAL CHARACTERISTICS (25° C Ambient Temperature unless otherwise noted) (Note 6)

CVAROL	CHARACTERISTIC	MIN	MAX	UNITS	TEST CONDITIONS
SYMBOL	CHARACTERISTIC	IVIIIN	WAX	UNITS	TEST CONDITIONS
BV <sub>CEO</sub>	Collector to Emitter Breakdown Voltage	-40		V	$I_{C} = 0.5 \text{ mA}, I_{B} = 0$
BV <sub>EBO</sub>	Emitter to Base Breakdown Voltage	-4.0		V	$I_E = 10 \ \mu \ A, \ I_C = 0$
Ісво	Collector Cutoff Current		50 1.0	nΑ μΑ	$V_{CB} = -30 \text{ V}, I_E = 0$ $V_{CB} = -30 \text{ V}, I_E = 0, T_A = 60^{\circ} \text{ C}$
h <sub>FE</sub>	DC Current Gain (Note 5)	150 90	300		$I_{C} = 2.0 \text{ mA}, V_{CE} = -10 \text{ V}$ $I_{C} = 100 \text{ mA}, V_{CE} = -10 \text{ V}$
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage (Note 5)		-0.5	V	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$
Сов	Output Capacitance		4.0	pF	$V_{CB} = -10 \text{ V}, I_E = 0, f = 100 \text{ kHz}$

## NOTES:

- 1. These ratings are limiting values above which the serviceability of any individual semiconductor device may be impaired.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
   These ratings give a maximum junction temperature of 150° C and (TO-92) junction-to-case thermal resistance of 125° C/W (derating factor of 8.0
- These ratings give a maximum junction temperature of 150° C and (TO-92) junction-to-case thermal resistance of 125° C/W (derating factor of 8.0 mW/° C); junction-to-ambient thermal resistance of 200° C/W (derating factor of 5.0 mW/° C); (TO-236) junction-to-ambient thermal resistance of 357° C/W (derating factor of 2.8 mW/° C).
- 4. Rating refers to a high current point where collector to emitter voltage is lowest.
- Pulse conditions: length = 300 μs; duty cycle = 1%
- 6. For product family characteristic curves, refer to Curve Set T215.
- Package mounted on 99.5% alumina 8 mm x 8 mm x 0.6 mm.